

# Synthesis, Properties, and Derivatization of Poly(dihydrogermane): A Germanium-based Polyethylene Analogue

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## Abstract

Polygermanes are germanium-based analogues of polyolefins and possess polymer backbones made up of catenated Ge atoms. In the present contribution we report the preparation of a stable germanium polyethylene analogue – polydihydrogermane (i.e.,  $(\text{GeH}_2)_n$ ) – via two straightforward approaches that involve topotactic deintercalation of the CaGe Zintl phase. The resulting  $(\text{GeH}_2)_n$  possess morphologically dependent chemical and electronic properties and thermally decompose to yield amorphous hydrogenated Ge. We also show that the resulting  $(\text{GeH}_2)_n$  provide a platform from which functionalized polygermanes can be prepared via thermally-induced hydrogermylation-mediated pendant group substitution. This facile one-step derivatization reaction exploits Ge–H reactivity and opens the door to a wide array of tailored functional polygermanes.

## Introduction.

Polyethylene (PE;  $(\text{CH}_2)_n$ ) is the prototypical polyolefin and is ubiquitous throughout modern society; its impact can be seen in seemingly unrelated sectors ranging from packaging to construction to communications and more than 21 million metric tonnes were produced in the United States alone in 2018.<sup>1</sup> The vast utility of PE arises, in part because it is readily prepared in large quantities, exhibits impressive chemical resistance, and it is processable. For silicon- and germanium-based polyolefin analogues the story is very different.

Polymers with backbones made up of catenated silicon (i.e., polysilanes) and germanium (i.e., polygermanes) atoms are far less prevalent. Correspondingly, their uses are not as far reaching; polysilanes are primarily employed as lithography resists<sup>2-4</sup> and polygermanes largely remaining as research curiosities.<sup>5-7</sup> The limited scope of impact of these materials arises in part because of complications related to preparation and reactivity. Still, they remain subjects of considerable interest because, unlike PE, their structures afford electrical conductivity that arises from  $\sigma$ -delocalization of electrons.<sup>8-10</sup> Furthermore, these electronic properties (in particular band gaps) can be tailored by defining molecule weight, side-group substitution, and/or introducing tensile strain.<sup>10-13</sup> As such, poly-silanes and germanes exhibit uniquely tunable optical and electrical properties, such as non-linear optical response<sup>14</sup> and photo-induced electron transfer.<sup>15</sup> If a Ge-based polyethylene analogue (i.e.,  $(\text{GeH}_2)_n$ ) can be prepared, it is reasonable it will provide additional fundamental insight into polymers made up of catenated non-carbon Group 14 elements

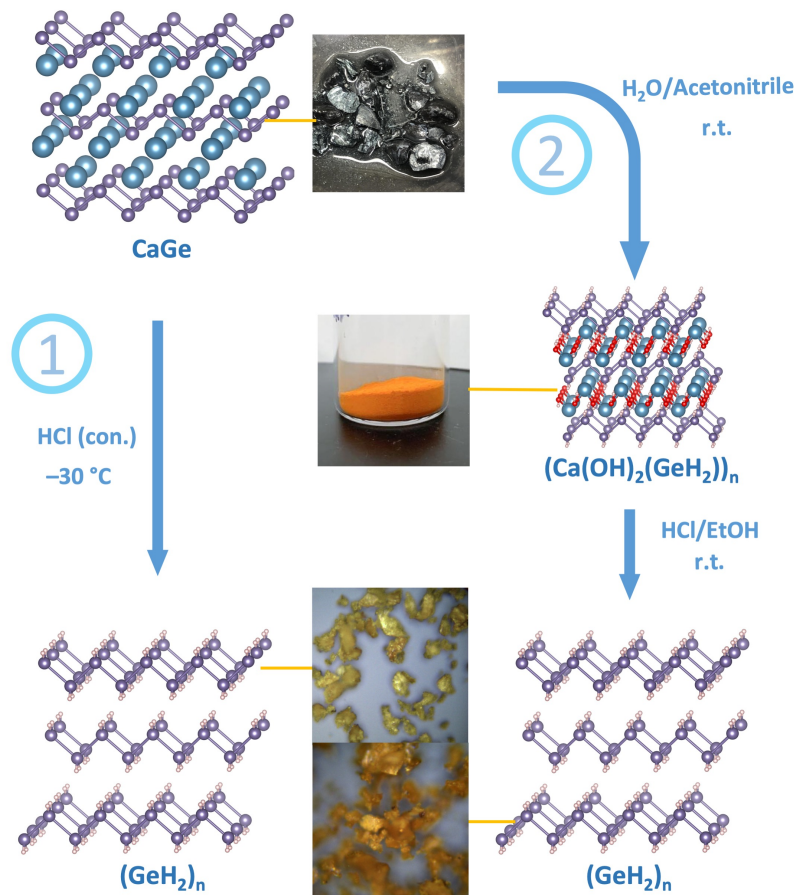
(i.e., Si and Ge) and their properties, while offering a platform on which a suite of new materials with exquisitely tunable optical and electronic properties can be developed.

Preparing polygermanes can be challenging; short chain oligogermanes have been synthesized from reactions involving Grignard or organolithium reagents with germanium diiodide,<sup>10,16,17</sup> higher molecular weight linear organopolygermanes are accessible from diorganodichlorogermane precursors via Würtz-type coupling<sup>5,10,14,16</sup> and electroreductive synthesis.<sup>12,18,19</sup> Alternative approaches employing Ru (i.e.,  $(\text{PMe}_3)_4\text{RuMe}_2$  or  $\text{Ru}(\text{PMe}_3)_4(\text{GeMe}_3)_2$ )<sup>17,20</sup> catalyzed demethanative coupling of methylgermanes have also been reported and provide inorganic/organic hybrids containing polygermanes or substituted polygermanes in high yields, however it is not unreasonable that catalyst residues would impact (even compromise) material electronic properties. Furthermore, while these reactions offer comparatively high molecular weight polymers, the scope of accessible substituents is limited by the availability of appropriate molecular precursors.

To our knowledge, only two historical reports have appeared that describe preparation of  $(\text{GeH}_2)_n$ . Reports by Royen et al.<sup>21,22</sup> suggest  $(\text{GeH}_2)_n$  could be topotactically liberated from CaGe. While these early contributions do not provide evidence in the context of modern characterization standards that  $(\text{GeH}_2)_n$  was realized, they did confirm the presence of Ge-H functionalities that could provide for post-synthesis modification using variations of

hydrogermylation protocols used to tailor Ge substrates,<sup>23</sup> nanostructures,<sup>24</sup> and layered polygermanes.<sup>25</sup>

We have drawn inspiration from these early reports and successfully prepared high quality  $(\text{GeH}_2)_n$  from CaGe at a gram-scale. In this contribution we describe two deintercalation approaches that afford  $(\text{GeH}_2)_n$  (Scheme 1) and interrogate the morphology, bonding, structural disorder, optical band gap, as well as thermal stability of the resulting products. In addition, we demonstrate that the  $(\text{GeH}_2)_n$  products are readily modified via the introduction of pendant alkyl chains by employing thermally-induced hydrogermylation.



Scheme 1. Two methods for preparing  $(\text{GeH}_2)_n$  from CaGe.

## Results and Discussion

Polyhydrogermanes (i.e.,  $(\text{GeH}_2)_n$ ) investigated in the present study were prepared via two complementary topotactic deintercalation methods from the Zintl phase CaGe (See: Electronic Supporting Information). CaGe was synthesized by pressing stoichiometric quantities of Ca and Ge metals into a pellet that was subsequently melted/annealed in an arc-furnace.<sup>25,26</sup> Powder X-ray diffraction (pXRD, Figure 1s) confirmed the as synthesized CaGe is highly crystalline and phase pure. The established crystal structure of CaGe shows linear chains of bonded germanium atoms in layers that are charge balanced by layers of Ca ions.<sup>27</sup> Under ambient conditions CaGe reacts with moisture (i.e., water) causing it to lose its metallic luster; this process is also accompanied by an obvious color change from grey to light yellow within minutes (Figure S2). The resulting yellow powder takes on a deep orange appearance after several days (Scheme 1). These observations are similar to those noted by Vogg et al. for the reaction of another germanium-based Zintl phase (i.e.,  $\text{CaGe}_2$ ) with water that leads to the formation of  $(\text{Ca}(\text{OH})_2\text{GeH})_n$ .<sup>28</sup>

Our first attempt to prepare  $(\text{GeH}_2)_n$  drew inspiration from a literature procedure first reported in 1933<sup>21</sup> that is similar to the method employed by us,<sup>25</sup> and others<sup>28–31</sup> to exfoliate hydride-terminated germanane from  $\text{CaGe}_2$  (Method 1, Scheme 1). This process involved direct reaction of CaGe with cold (i.e.,  $-30\text{ }^\circ\text{C}$ ) concentrated HCl.<sup>21,27</sup> To our surprise, and in stark contrast to the established  $\text{CaGe}_2$  reaction that is slow and requires days to complete,<sup>25,31</sup> the reaction with CaGe is very exothermic and violent causing CaGe to break down quickly (i.e., within minutes); in fact,

the entire deintercalation reaction being complete within ca. 30 minutes. Consistent with previous reports,<sup>22</sup> products of this reaction are not stable when dry and detonate loudly with visible sparks when manipulating  $\geq$  ca. 0.25 g of dry powder under ambient conditions. Similar decomposition was noted for milligram material quantities upon exposure to a standard anti-static gun or 1.99 mW laser. Clearly, extreme caution must be exercised when performing this reaction and manipulating the corresponding products. Unfortunately, the sensitivity of the cold acid liberated  $(\text{GeH}_2)_n$  limited comprehensive characterization, however the analyses we could perform provides valuable insight into the material structure and properties.

In light of the violent nature of the direct reaction of CaGe with cold acid and the sensitivity of the reaction products, we chose to explore alternative methods that could surmount these challenges. Our qualitative observations of trace water (i.e., ambient humidity) induced oxidation of CaGe held the key to developing a new two-step approach for preparing  $(\text{GeH}_2)_n$  (Method 2, Scheme 1). In this case, CaGe powders were exposed to a solvent mixture of deionized water and acetonitrile to afford an orange solid after approximately 24 h. This intermediate product was isolated by centrifugation and subsequently washed/centrifuged in cold 1:5 v/v HCl/EtOH. The  $(\text{GeH}_2)_n$  prepared in this way is readily handled as a dry powder under ambient conditions in large (i.e.,  $\geq 2.0$  g) quantities, however it does decompose to provide a black solid upon prolonged (i.e., 1 min) exposure to a laser (Figure S3)

To investigate the bonding within the products obtained from the two methods described herein we employed Fourier-transform infrared (FTIR), Raman, and X-ray photoelectron

spectroscopy (XPS) (Figure 1). Consistent with the formation of  $(\text{GeH}_2)_n$ , the FTIR spectrum of the freshly prepared orange product obtained from cold acid deintercalation of CaGe (i.e., Method 1) shows intense Ge–H<sub>2</sub> stretching (2042 - 2046 cm<sup>-1</sup>) and bending (ca. 776 and 831 cm<sup>-1</sup>) modes.<sup>30</sup> Additional O–H stretching and bending features at ~3370 and 1630 cm<sup>-1</sup> are attributed to adsorbed water.<sup>25,32</sup> For the two-step water oxidation/acid deintercalation process (i.e., Method 2) we first interrogated the orange product obtained from water-induced oxidation of CaGe and found the FTIR spectrum (Figure S4) showed the abovementioned features associated with Ge–H<sub>2</sub>, as well as an additional sharp absorption at 3645 cm<sup>-1</sup> that is characteristic Ca(OH)<sub>2</sub> stretching – based upon these observations we contend that this material is ‘ $(\text{Ca}(\text{OH})_2\text{GeH}_2)_n$ ’.<sup>33</sup> Acid treatment of the ‘ $(\text{Ca}(\text{OH})_2\text{GeH}_2)_n$ ’ provided an orange product that is qualitatively identical (other than stability) to the product recovered from cold acid deintercalation and the FTIR spectrum of this material (Figure 1a) is fully consistent with this proposal.

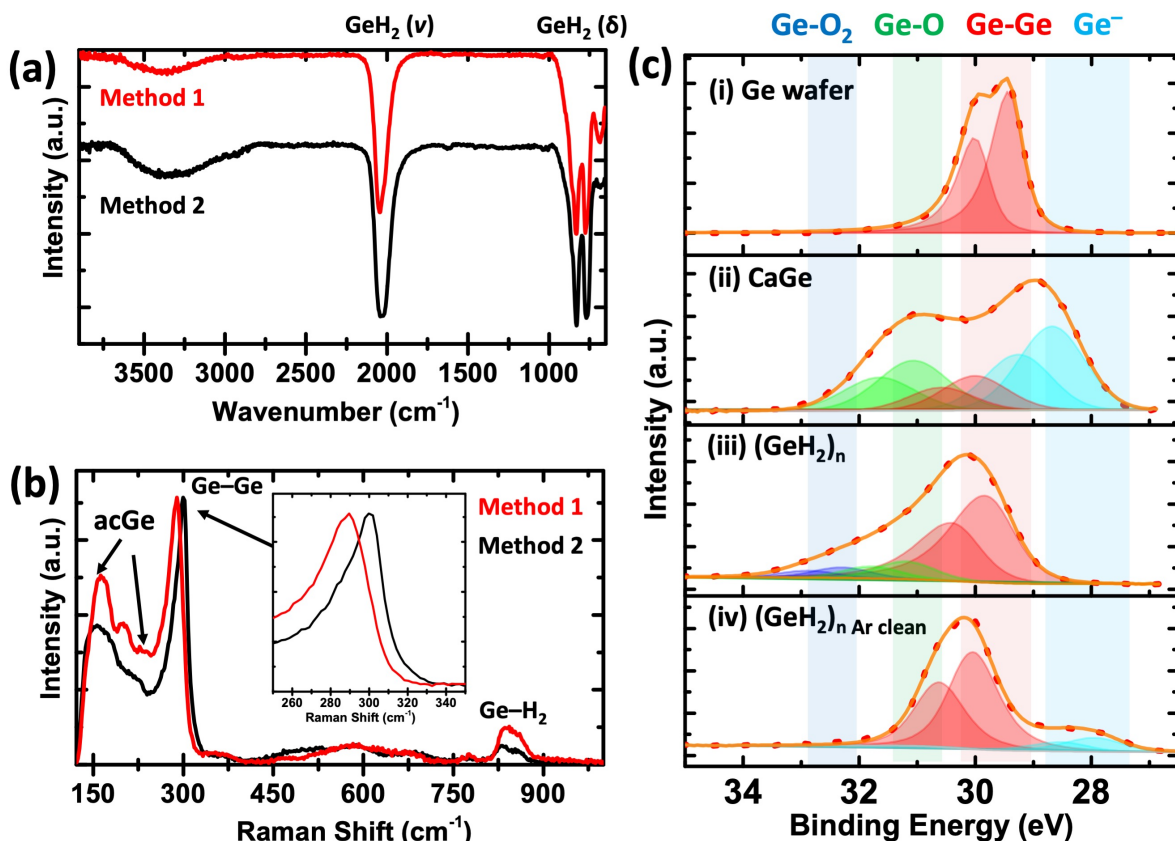


Figure 1. (a) FTIR and (b) Raman spectroscopy of (GeH<sub>2</sub>)<sub>n</sub> synthesized by Method 1 and 2, inset: highlighting Ge-Ge peak center. (c) High resolution XP spectra of Ge 3d region, (i) Ar plasma cleaned Ge (111) wafer, (b) CaGe after Ar plasma cleaning, (GeH<sub>2</sub>)<sub>n</sub> prepared by method 2, (c) before and (d) after Ar plasma cleaning.

Raman spectroscopy provides further support that (GeH<sub>2</sub>)<sub>n</sub> is being formed with the appearance of an absorption associated with a Ge-Ge optical phonon at 289 and 300 cm<sup>-1</sup> for products prepared using Methods 1 and 2, respectively (Figure 1b). Consistent with FTIR analyses, additional Ge-H<sub>2</sub> vibrations are also noted at 180 and 820 cm<sup>-1</sup>. For (GeH<sub>2</sub>)<sub>n</sub> prepared using rapid cold acid deintercalation of CaGe, a red-shift in the Ge-Ge optical phonon is observed compared to that of bulk Ge crystal (300 cm<sup>-1</sup>).<sup>34</sup> This observation is reasonably ascribed to a disorder-induced activation of phonon density, as described by Weinstein and Cardona,<sup>35</sup> and is consistent with our TEM and DRA data (vide infra). In addition to optical phonons, acoustic-like Ge (acGe)

features at  $\sim 160\text{-}170\text{ cm}^{-1}$  and  $\sim 225\text{ cm}^{-1}$  contributed by the vibration of  $(\text{GeH}_2)_n$  chains were observed.<sup>36</sup> More intense, blue-shifted acGe peaks were noted in the spectrum of  $(\text{GeH}_2)_n$  prepared using the two step water oxidation/acid deintercalation approach (Method 2); this difference is reasonably attributed to a closer packing of  $(\text{GeH}_2)_n$  chains that is also evident in our pXRD analyses (vide infra).

XPS provides insight into the elements present within a given material, as well as their corresponding bonding environments and oxidation states. Unfortunately, this analysis was not possible of the  $(\text{GeH}_2)_n$  obtained from Method 1 because of its noted sensitivity, however we gained valuable insight into the composition of the product of Method 2. For the present investigation, all spectra were calibrated to adventitious carbon that was set to a binding energy (BE) of 284.8 eV.<sup>37,38</sup> Survey spectra (Figure S5) show emissions from elements consistent with the expected composition (Note: Evidence of surface oxidation was observed in the spectrum of CaGe (Figure S6)). High-resolution XP spectra of Ge 3d region were fit to the Ge 3d<sub>5/2</sub> and 3d<sub>3/2</sub> spin-orbit couple and corresponding couples for different Ge species are presented in Figure 1c as the same color. For CaGe, a low binding energy component centered at 28.62 eV was identified and is a comparable binding energy to Ge in CaGe<sub>2</sub>; of important note, this emission appears at a significantly lower binding energy than that of the reference elemental Ge (29.45 eV).<sup>25</sup> This observation is consistent with the Zintl phase concept that is routinely applied to the understanding of bonding within CaGe.<sup>39,40</sup> The XP spectrum of as prepared  $(\text{GeH}_2)_n$  obtained from Method 2 shows an intense emission at 29.82 eV (Figure 1c(iii)); as expected this is marginally higher than

the binding energy of Ge in germanium metal because of the presence of electronegative hydrogen termination. We also observe evidence of trace surface oxidation (i.e., Ge–O (31.1 eV) and Ge–O<sub>2</sub> (32.5 eV)) that results from sample preparation and manipulation.<sup>41</sup> All oxygen-based features are removed upon exposure to an Ar plasma and the Ge emission attributed to (GeH<sub>2</sub>)<sub>n</sub> appears at a BE of 30.06 eV. In addition, while Ca emissions were not detected in the survey spectrum because they overlap with the Ge LMM signal at ca. 346 eV and Ge 3d emission at ca. 30 eV, a residual peak centered at 27.90 eV is noted and can only be assigned to Ge (–2) arising from residual CaGe that was not deintercalated.

Further insight into the solid-state structure of the present (GeH<sub>2</sub>)<sub>n</sub> assemblies is obtained from the PXRD patterns of the (GeH<sub>2</sub>)<sub>n</sub> obtained using synchrotron radiation ( $\lambda = 0.68745$  Å). The patterns from the products of Methods 1 and 2 show broad reflections appearing at ca. 12, 21, 34 and 42° consistent with short range nanostructured order (Figure 2a). In addition to these reflections, we note low intensity baseline resolved reflections attributable to trace crystalline CaOCl<sub>2</sub>·3H<sub>2</sub>O in the pattern of the (GeH<sub>2</sub>)<sub>n</sub> obtained from the controlled water oxidation approach (i.e., Method 2). Drawing on past experience with CaGe<sub>2</sub>,<sup>25</sup> the observation of broad reflections is consistent with topotactic removal of the calcium ions. In this context, we have indexed the patterns in Figure 2a based upon an orthorhombic unit cell. Doing so reveals that the first two reflections in the pattern correspond to (021) and (200) (Figure S7) where the (200) represents half of the distance between co-planar (GeH<sub>2</sub>)<sub>n</sub> chains. These dimensions appeared at 3.28 Å (021) and 1.84 Å (200) for the product obtained from cold acid treatment (Method 1) and

3.35 Å (021) and 1.87 Å (200) for the product obtained from our two-step water oxidation approach (i.e., Method 2). In both cases, the (021) plane separation approaches that of bulk Ge (111) (3.324 Å) while the (200) plane shrinks significantly compare to the parent CaGe (2.288 Å).<sup>27,42</sup> These data suggest the Ca ions are being removed from CaGe being replaced by hydrogen atoms; this process results in the (Ge)<sub>n</sub> chains being ca. 20 % closer to one another (Figure 2b). This structural change disturbs the packing of the (GeH<sub>2</sub>)<sub>n</sub> chains along the b axis and no (020) reflection is observed.

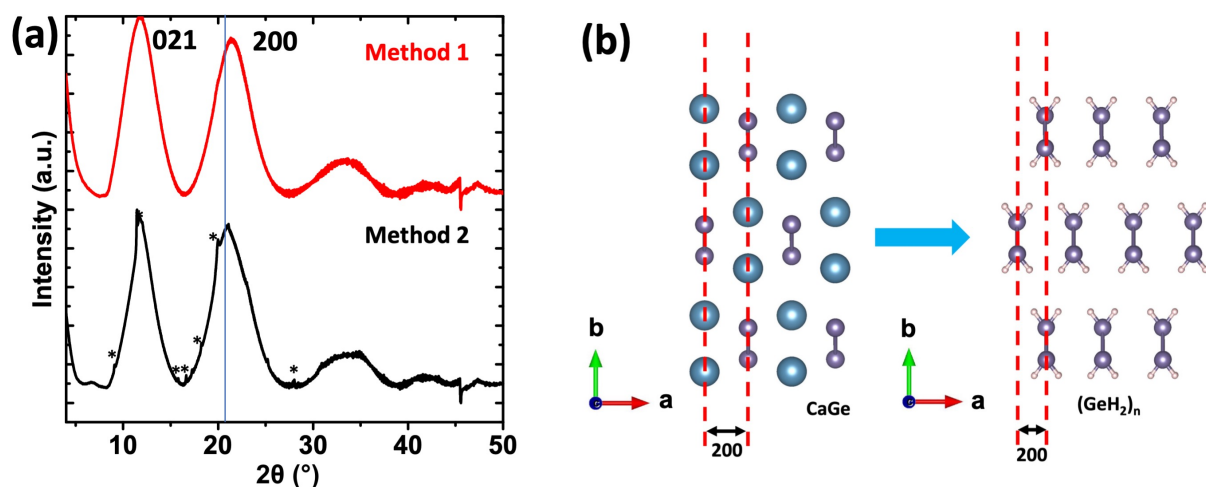


Figure 2 (a) Powder XRD pattern of (GeH<sub>2</sub>)<sub>n</sub> by two methods,  $\lambda = 0.68745$  Å, \*trace CaOCl<sub>2</sub>·3H<sub>2</sub>O and (b) Schematic illustration of (200) reflection from (left) CaGe and (right) (GeH<sub>2</sub>)<sub>n</sub>.

Electron microscopy reveals differences in the morphologies of the two ‘types’ of (GeH<sub>2</sub>)<sub>n</sub> that could impact their material properties (Figure 3). Imaging of the (GeH<sub>2</sub>)<sub>n</sub> provided by Method 1 reveals a random structure while the products of Method 2 shows structural ordering that qualitatively resembles the orientation of ‘Ge<sub>n</sub>’ chains within the crystalline CaGe starting material

and supports the proposal of topotactic extraction of the Ca ions. It is reasonable this morphological difference reflects the vigorous nature of Method 1 that likely compromises the integrity of the  $(\text{GeH}_2)_n$  network. The gentler Method 2 preserves the underlying ‘ $\text{Ge}_n$ ’ within the parent CaGe.

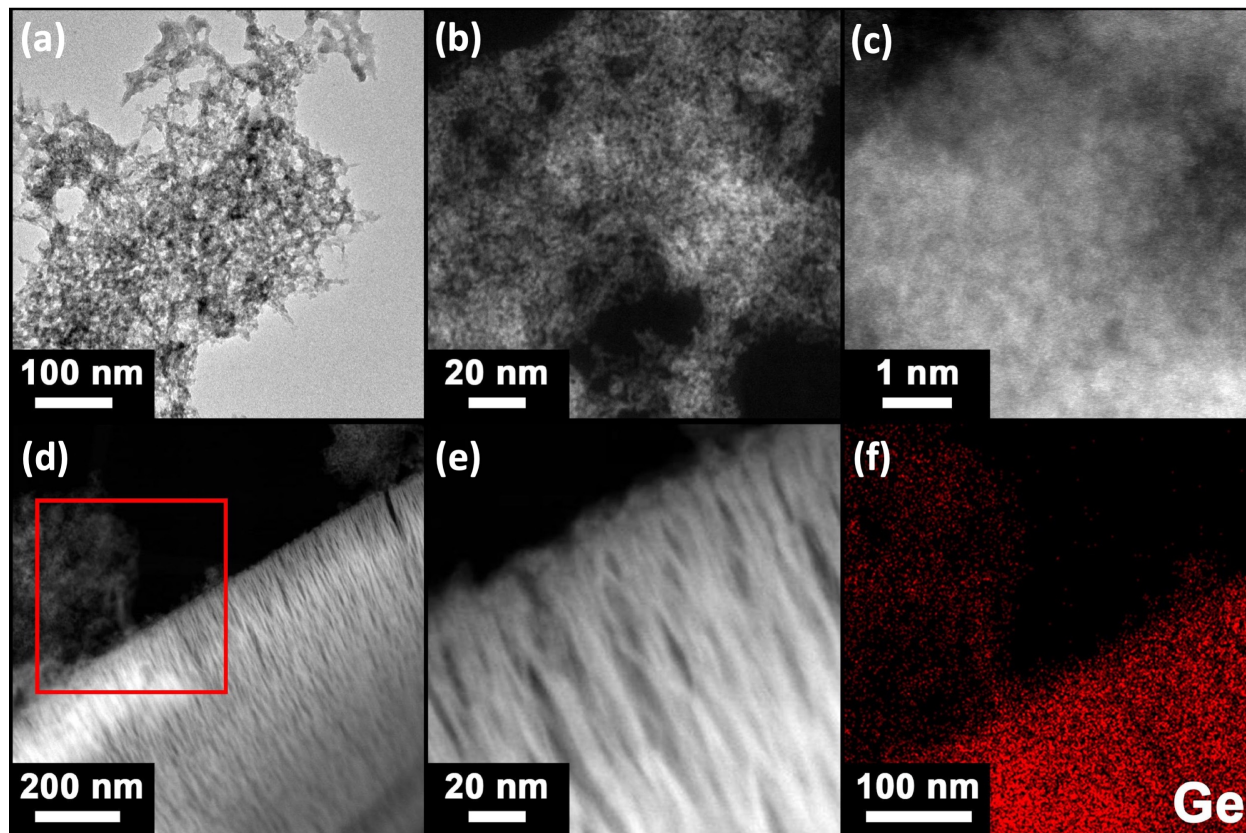


Figure 3. (a-c) TEM analysis of  $(\text{GeH}_2)_n$  Prepared by Method 1: (d) low magnification TEM image, (e) high magnification and (f) atomic resolution HAADF-STEM images. (a-c) TEM analysis of  $(\text{GeH}_2)_n$  Prepared by Method 2: (d) low magnification image and (e) high magnification HAADF-STEM images, (f) EDX mapping of Ge  $K\alpha$  at area selected in (d);

Electron microscopy comes with the opportunity to map material composition as a function of morphology using energy dispersive X-ray (EDX) analyses. Consistent with the XPS study presented above, EDX mapping the two  $(\text{GeH}_2)_n$  morphologies indicates both are comprised primarily of Ge (Figure S8). Furthermore, the EDX spectra are dominated by intense features

associated with Ge (i.e.,  $L\alpha$ ,  $L\beta$ ,  $K\alpha$ ,  $K\beta$ ) as well as trace O (ca. 2 %) and Cl (ca. 2.5 %). No Ca is detected at the sensitivity of the EDX method.

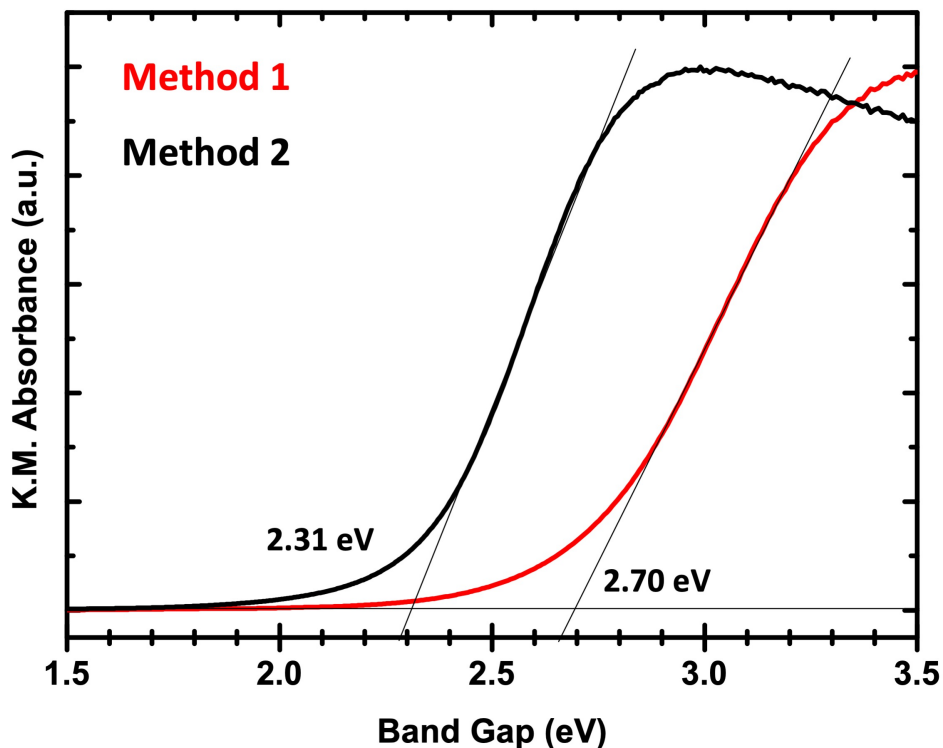


Figure 4. Diffuse reflectance absorption plots for  $(\text{GeH}_2)_n$  prepared by Method 1 (red) and 2 (black), showing optical band gaps of 2.31 and 2.70 eV, respectively.

Having identified the composition and morphology of the  $(\text{GeH}_2)_n$  obtained from the CaGe deintercalation using Methods 1 and 2, we turned our attention to their respective material properties. Diffuse reflectance absorption (DRA, Figure 4) provides convenient determination of the material optical band gap. For the present  $(\text{GeH}_2)_n$  samples, optical band gap depends upon mode of preparation and is a reflection of their morphology; optical band gaps of 2.70 and 2.31 eV were obtained for  $(\text{GeH}_2)_n$  prepared using Methods 1 and 2, respectively. We also note that

while Urbach tails were observed for both samples, it is more prevalent for  $(\text{GeH}_2)_n$  prepared using Method 1 and reflects a lack of long range order in the material.<sup>30,43</sup>

The experimental values reported here agree well with first principles calculations reported by Zeng et al.<sup>11</sup> who predicted a  $(\text{GeH}_2)_n$  band gap of 3.03 eV. These authors indicated that band-edge states in  $(\text{GeH}_2)_n$  arise primarily from the atomic orbital delocalized over the Ge backbone; in these systems the lowest unoccupied molecular orbital (i.e., LUMO; conduction band edge) arises from Ge 4s and 4p<sub>x</sub> orbitals while the highest occupied molecular orbital (i.e., HOMO; valence band edge) is dominated by the Ge 4p<sub>z</sub> (along the Ge-Ge chain). Based upon these findings Zeng et al. suggested introducing bulky pendant functionalities (e.g., replacement of Ge-H with Ge-phenyl) would result in negligible impact on the band gap and demonstrated computationally that introducing mechanical (e.g., tensile and compressive) strain provided band gap tuning.<sup>11</sup> For the present ‘real-life’ samples, because the  $(\text{GeH}_2)_n$  are obtained from CaGe and possess the same pre-existing Ge–Ge skeleton, it is reasonable that the apparent method dependent band gap arises as a consequence differences in the structural strain within the products.

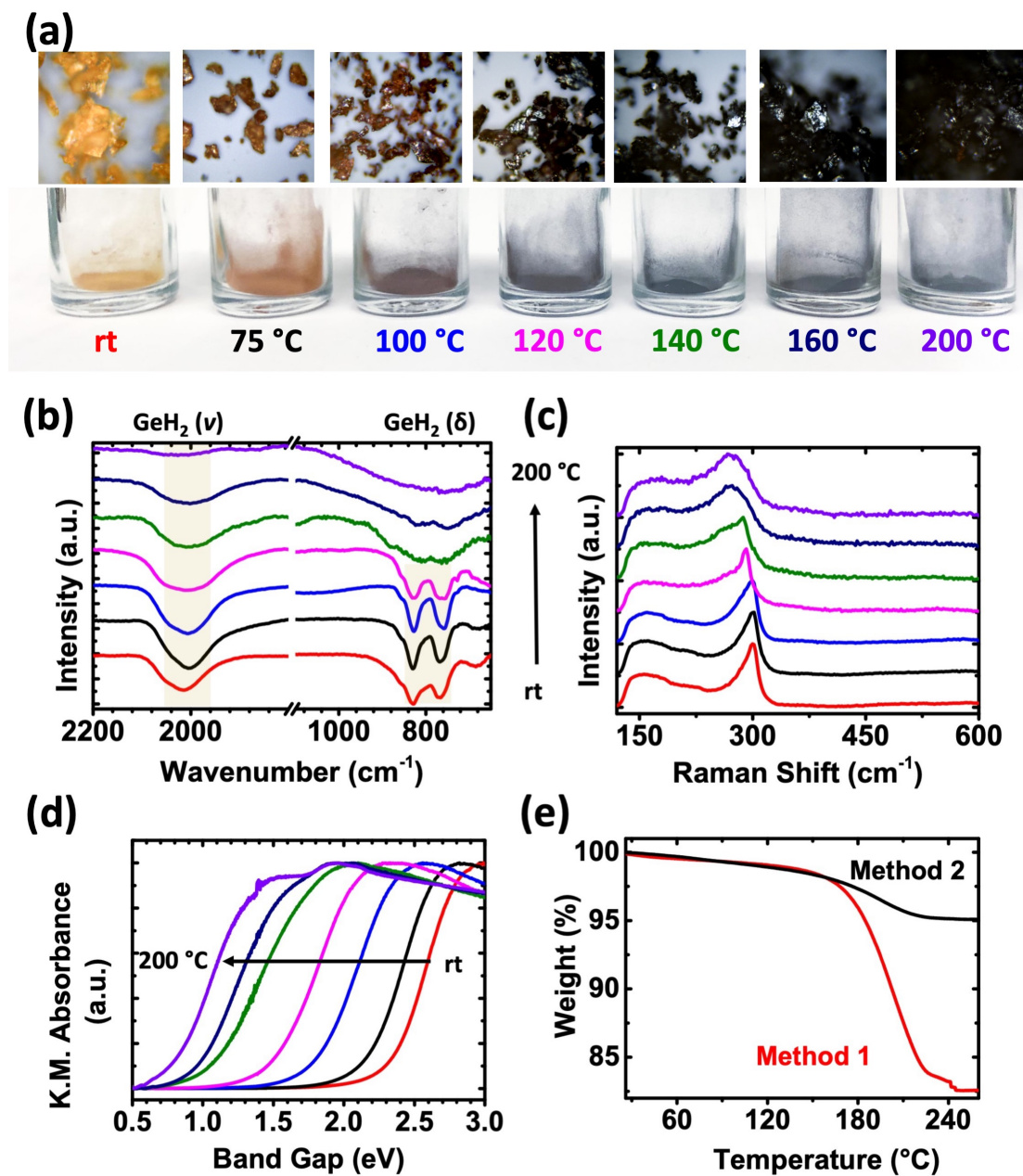
### **Thermal Stability**

The thermal stability of  $(\text{GeH}_2)_n$  prepared using Method 2 was evaluated using FTIR, Raman spectroscopy and DRA after they had been heated to predefined temperatures in the range of 75 to 200 °C in an inert environment (i.e., Ar atmosphere and subdued light) for 4 hours (Figures 5 a-d). The first, and most immediately striking observation is the noted change in colour. The apparent

colour of the samples evolved from gold to brown and eventually to black with increased temperature. FTIR and Raman spectra obtained from samples heated at, or below 120 °C (i.e., magenta traces in Figure 5) show negligible differences from the parent material (i.e., red traces in Figure 5). Increasing the processing temperature to above 120 °C saw the intensity of Ge–H<sub>2</sub> bending modes in the FTIR spectrum diminish (and eventually disappear) and a broad Ge–O–Ge stretching mode appears that we attribute to material handling. Raman spectra show a similar transition point at ca. 120 °C at which the Ge–Ge feature red-shifted presumably due to increased structural disorder; this red-shift is accompanied with feature broadened at higher temperatures. The observations made in the FTIR and Raman spectra suggest heating (GeH<sub>2</sub>)<sub>n</sub> to above 120 °C induce dehydrogenative reactions that cause the Ge–Ge skeleton to collapse yielding amorphous Ge. Consistent with this proposal we note the optical band gap decreases from 2.31 eV for as prepared samples to 1.50 eV for samples heated at 120 °C. This decrease in band gap is accompanied by an appearance of a more pronounced Urbach tail. Heating at 140 °C (green line) sees the band gap decrease further to 1.06 eV – a value comparable with amorphous hydrogenated germanium film (1.1 eV),<sup>44</sup> and continues to drop to 0.73 eV for sample cured at 200 °C. For samples cured at higher than 140 °C, the Urbach tails become less prevalent suggesting the formation of a more ordered structure.

TGA was performed for (GeH<sub>2</sub>)<sub>n</sub> prepared by both methods to interrogate their evolution with heating (Figure 5d). A gradual 2 % weight loss was observed for both materials upon heating to 150 °C that we attribute to the liberation of ~ 0.75 eq. of hydrogen. This temperature is lower than

that observed for layered germanane (200–250 °C).<sup>25,30</sup> A second weight loss event (i.e., 16 % and 3 % for (GeH<sub>2</sub>)<sub>n</sub> from Methods 1 and 2, respectively) was noted between 180 and 220 °C. The 16 % weight loss noted for Method 1 materials is an order magnitude higher than what would be expected if the entire hydrogen content was liberated from (GeH<sub>2</sub>)<sub>n</sub>. This large weight loss is likely a reflection of the morphological differences between Method 1 and 2 materials noted in our TEM analysis that show Method 1 materials are smaller randomly shaped pieces that would bear more terminal -GeH<sub>3</sub> functionalities than the ordered linear structures prepared using Method 2. As such, we attribute this additional weight loss to the liberation of low molecular weight germanes (i.e., Ge<sub>x</sub>H<sub>2x+2</sub>).<sup>45</sup> If one reasonably assumes the low molecular weight germanes obtained upon heating Method 1 materials are primarily germane (GeH<sub>4</sub>), the 16 % weight loss corresponds to ca 0.24 eq. of hydrogen. In contrast, for Method 2 materials, which would be expected to contain far fewer terminal groups, the noted 3 % weight loss provides a hydrogen loss of ca. 0.2 eq. and GeH<sub>4</sub> loss of ca. 0.02 equivalent.



**Figure 5.** (a-d)  $(\text{GeH}_2)_n$  annealed at various temperature in Ar environment: (a) optical image, (b) FTIR spectra, (c) Raman spectra and (d) DRA spectra. (e) TGA analysis of  $(\text{GeH}_2)_n$  prepared by Methods 1 and 2.

## Surface Functionalization

With  $(\text{GeH}_2)_n$  in hand, we explored their reactivity and demonstrated side group substitution using thermally-induced hydrogermylation reactions.<sup>23,24,46,47</sup> Functionalization was achieved by reacting  $(\text{GeH}_2)_n$  (10 mg, 0.13 mmol  $\text{GeH}_2$ ) and 1-dodecene (2.0 mL, 2.6 mmol) in 10 mL dry toluene. The reaction mixture was subsequently ultrasonicated in a bath sonicator for 3-hours after which it was heated to and maintained at 150 °C and stirred for 15 hours. Consistent with differing degrees of functionalization, the products obtained from non-sonicated reaction mixtures exhibited limited solvent compatibility while those from sonicated mixtures are compatible with organic solvents and remain in solution for months.

The FTIR spectra (Figure 6) obtained from the reactions involving 1-dodecene with  $(\text{GeH}_2)_n$  obtained from Methods 1 and 2 were identical and show the expected features of pendant dodecyl groups and no evidence of unsaturated features (i.e., C–H  $\text{sp}^2$  stretching and C=C vibrations) of 1-dodecene. Consistent with our qualitative observations of solubility, the FTIR spectra products from reaction mixtures that were not sonicated show Ge–H features at ca. 830 and ca. 2010  $\text{cm}^{-1}$  (Figure 6 b,c). This suggests that in these cases the  $(\text{GeH}_2)_n$  was incompletely exfoliated and only partially functionalized (i.e., the product corresponds to  $(\text{GeH}_x(\text{C}_{12}\text{H}_{25})_{2-x})_n$ ). No such Ge–H features were evident in the spectra of products from sonicated reaction mixtures.

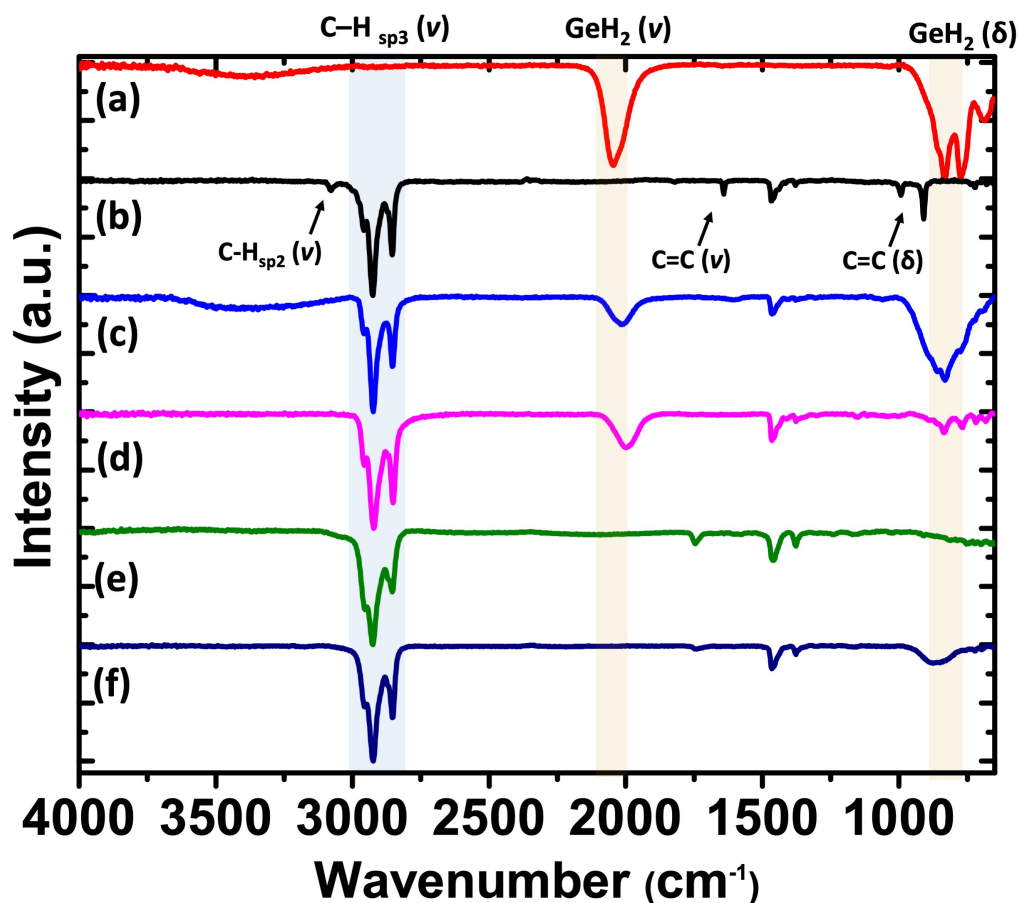


Figure 6. FTIR spectra of (a)  $(\text{GeH}_2)_n$  prepared by Method 1, (b) neat 1-dodecene,  $(\text{GeH}_x(\text{C}_{12}\text{H}_{25})_{2-x})_n$  prepared without sonication from (c) Method 1 and (d) Method 2,  $(\text{Ge}(\text{C}_{12}\text{H}_{25})_2)_n$  prepared with sonication from (e) Method 1 and (f) Method 2.

EDX mapping of the present  $(\text{GeH}_x(\text{C}_{12}\text{H}_{25})_{2-x})_n$  and  $(\text{Ge}(\text{C}_{12}\text{H}_{25})_2)_n$  confirm C and Ge signals are coincident for all samples (Figure 7 c, d and S9). Consistent with our proposal that sonication is necessary to exfoliate  $(\text{GeH}_2)_n$  prior to modification via thermally-induced hydrogermylation, HAADF-STEM analyses shows structures of similar morphology to that observed for the parent  $(\text{GeH}_2)_n$  (Figure 7); taking into consideration our EDX data, this suggests the hydrogermylation reaction may only proceed on the surface of the  $(\text{GeH}_2)_n$  assemblies.

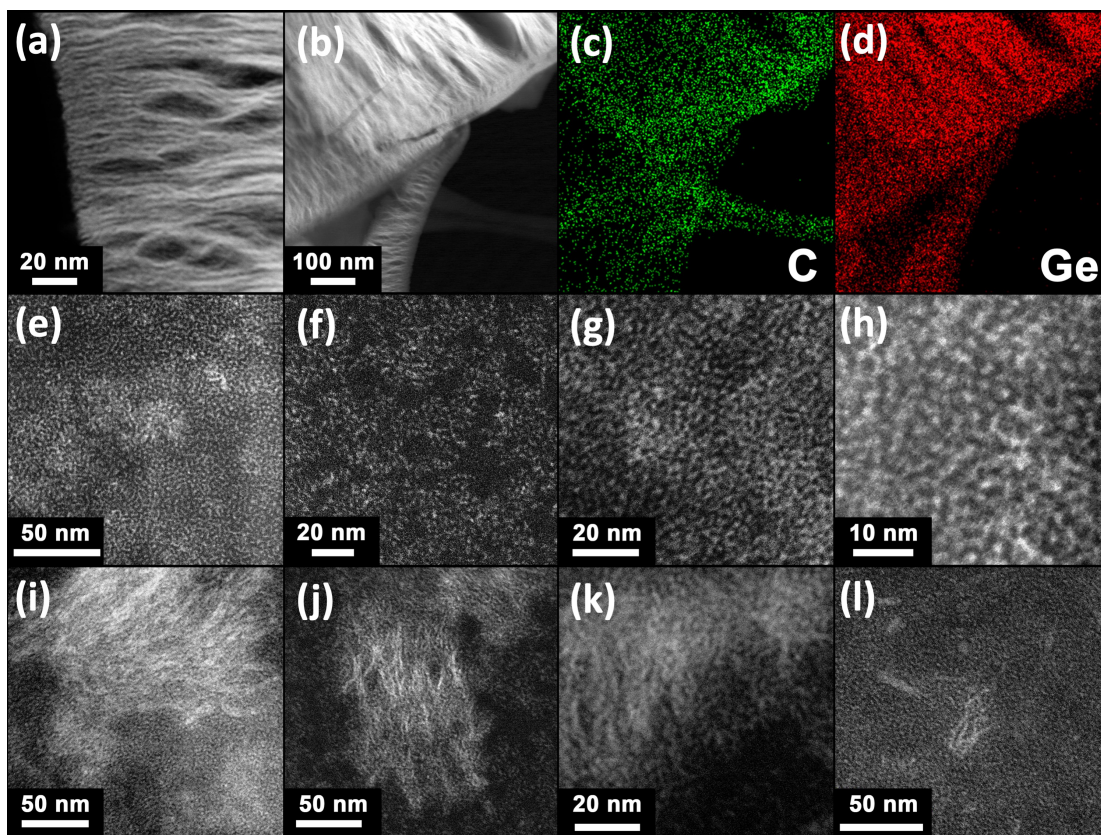


Figure 7. HAADF-STEM images of  $(\text{Ge}(\text{C}_{12}\text{H}_{25})_2)_n$  prepared using Method 2. (a-d) without sonication: (a) high-resolution image, (b) low-resolution image, (c) C K $\alpha$  mapping at area (b), and (d) Ge K $\alpha$  mapping at area (b); (e-h) the assembly of freestanding  $(\text{Ge}(\text{C}_{12}\text{H}_{25})_2)_n$  at different magnification; (i-l) exfoliation process and break down of long Ge-Ge chains.

Evaluation of the products of the sonicated reactions using HAADF-STEM presents a very different picture. Images (Figures 7e-h, S10 c,d) show uniformly distributed patterns on the ultra-thin carbon support consistent with the  $(\text{Ge}(\text{C}_{12}\text{H}_{25})_2)_n$  being fully (or near fully exfoliated in solution). We further analyzed the non-fully exfoliated Ge-Ge strands (Figure 7i-l), and noticed the  $(\text{GeH}_2)_n$  does not remain a single linear strand. Instead, large fibers will directly decouple into smaller pieces with similar width, explains the narrow distribution for their sizes. Unfortunately, it is challenging to study the fine structure of these materials as images were blurred due to ligand

coverage, and attempted sample cleaning will alter their morphologies (Figure S11). This will be the basis of future investigations.

Consistent with FTIR and TEM analysis, near identical DRA, Raman, and XP spectra were obtained for products obtained from the functionalization of starting materials obtained from Methods 1 and 2 (Figure S12). This suggests that, despite the parent  $(\text{GeH}_2)_n$  having qualitatively different structures and stabilities, the  $(\text{Ge}(\text{C}_{12}\text{H}_{25})_2)_n$  the same (at the sensitivity of the methods employed). While straightforward heating of  $(\text{GeH}_2)_n$  above 140 °C provides a material a band gap approaching 1.06 eV,  $(\text{Ge}(\text{C}_{12}\text{H}_{25})_2)_n$  heated at the higher temperatures required for hydrogermylation (i.e., 150 °C) and longer times (15 h vs. 4 h) possess a band gap of 2.2 eV (Figure 12a). This is likely due the liquid-solid hydrogermylation reaction between 1-dodecene and  $(\text{GeH}_2)_n$  proceeding more rapidly than the solid-solid dehydrogenative reaction of  $(\text{GeH}_2)_n$  with itself.

## Conclusions

In summary, we have prepared stable germanium-based polyethylene analog. This polydihydrogermane is comprised of 'GeH<sub>2</sub>' repeat unit and retains a network structure consisting of aligned (GeH<sub>2</sub>)<sub>n</sub> chains present in the CaGe precursor. XRD shows it has a slightly larger interstrand distance compare with polydihydrogermane prepared in previous reports, which leads to a red-shift in the transverse acoustic vibration in Raman spectroscopy. Thermal stability measurements reveal that this stable form only proceed dehydrogenation reaction slowly with trace GeH<sub>x</sub> decomposition byproducts due to a stronger Ge–Ge bond compared with the traditionally method. Lastly, we show both forms of polydihydrogermane can be modified via hydrogermylation reaction, offering the opportunity for various functional catenated polygermanes.

## Associated Content

Supporting Information.

This material is available free of charge via the internet at <http://pubs.acs.org>.

PXRD of measured and calculated CaGe, optical photos of CaGe after exposure in ambient, optical microscopy photo of (GeH<sub>2</sub>)<sub>n</sub> damaged by laser power, FTIR spectrum of (Ca(OH)<sub>2</sub>GeH<sub>2</sub>)<sub>n</sub>, XPS survey spectra of Ge(111), CaGe, and (GeH<sub>2</sub>)<sub>n</sub>, high-resolution XP C 1s and Ca 2p spectra of CaGe, structure model of (GeH<sub>2</sub>)<sub>n</sub>, EDX spectra of (GeH<sub>2</sub>)<sub>n</sub> and functionalized polygermane, STEM images of (Ge(C<sub>12</sub>H<sub>25</sub>)<sub>2</sub>)<sub>n</sub>, DRA, Raman and XP spectra of functionalized polygermane.

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### Notes

The authors declare no competing financial interest.

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